

## KSD1589

### Low Frequency Power Amplifier Low Speed Switching Industrial Use

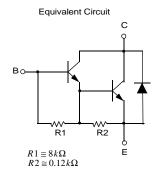
• Complement to KSB1098



## **NPN Silicon Darlington Transistor**

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	150	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	100	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
I <sub>C</sub>	Collector Current (DC)	5	Α	
I <sub>CP</sub>	*Collector Current (Pulse)	8	Α	
I <sub>B</sub>	Base Current	0.5	Α	
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.5	W	
	Collector Dissipation (T <sub>C</sub> =25°C)	20	W	
T <sub>J</sub>	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C	



## Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 100V, I_{E} = 0$			1	μΑ
h <sub>FE1</sub>	*DC Current Gain	$V_{CE} = 2V, I_{C} = 3A$	2K	6K	15K	
h <sub>FE2</sub>		$V_{CE} = 2V, I_{C} = 5A$	500			
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage	$I_C = 3A$ , $I_B = 3mA$		0.9	1.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 3A$ , $I_B = 3mA$		1.6	2	V
t <sub>ON</sub>	Turn On Time	$V_{CC} = 50V, I_{C} = 3A$		1		μs
t <sub>stg</sub>	Storage Time	$I_{B1} = -I_{B2} = 3mA$		3.5		μs
t <sub>f</sub>	Fall Time	$R_L = 16.7\Omega$		1.2		μs

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

## h<sub>FE</sub> Classification

Classification	R	0	Υ
h <sub>FE1</sub>	2000 ~ 5000	3000 ~ 7000	5000 ~ 15000

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

# **Typical Characteristics**

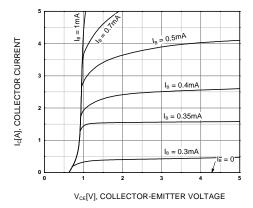


Figure 1. Static Characteristic

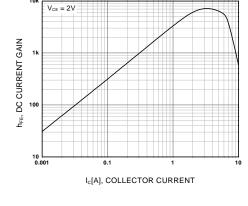


Figure 2. DC current Gain

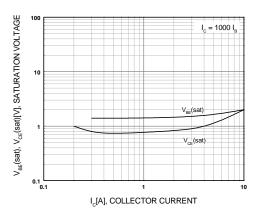


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

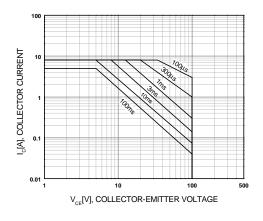


Figure 4. Safe Operating Area

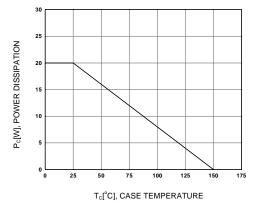
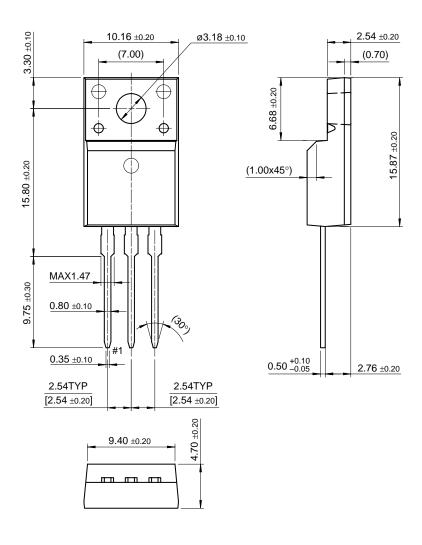


Figure 5. Power Derating

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# **Package Dimensions**

## TO-220F



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